LITE ON SEMICONDUCTOR

MBRF1060

All Dimensions in millimeter

REVERSE VOLTAGE - 60 Volts SCHOTTKY BARRIER RECTIFIERS FORWARD CURRENT - 10 Amperes ITO-220AC **FEATURES** • Metal of silicon rectifier, majority carrier conducton ITO-220AC • Guard ring for transient protection DIM. MIN. MAX. • Low power loss, high efficiency А 15.50 16.50 • High current capability, low VF В 10.0 10.40 · High surge capacity С 3.50 3.00 • Plastic package has UL flammability classification D 9.00 9.30 94V-0 Е 2.90 3.60 PIN • For use in low voltage, high frequency inverters, free F 13.46 14.22 whelling, and polarity protection applications G 1.15 1.70 н 4.83 5.33 I. 0.75 1.00 J 0.45 0.70 Κ 3.00Ø 3.30 Ø **MECHANICAL DATA** L 4.36 4.77 • Case : ITO-220AC molded plastic Μ 2.48 2.80 • Polarity : As marked on the body 2.80 Ν 2.50

PIN 1 -

PIN 2 -

- Weight : 0.06 ounces, 1.70 grams
- Mounting position : Any
- Max. mounting torque = 0.5 N.m (5.1 Kgf.cm)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

CHARACTERISTICS	SYMBOL	MBRF1060		UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	60		V
Maximum RMS Voltage	VRMS	42		V
Maximum DC Blocking Voltage	VDC	60		V
Maximum Average Forward Rectified Current (See Fig.1) @Tc=125°	C I(AV)	10		Α
Peak Forward Surge Current8.3ms single half sine-waveTA =25°C	; IFSM	150		А
Maximum Forward Voltage at TJ =25℃	VF	0.65		v
Maximum DC Reverse Current @TJ =25° at Rated DC Blocking Voltage @TJ =125°		0.1 25		mA
Typical Thermal Resistance (Note 1)	Rejc	2.5		°C/W
Typical Junction Capacitance (Note 2)	CJ	400		pF
Operating Temperature Range	TJ	-55 to +150		°C
Storage Temperature Range	Tstg	-55 to +175	-55 to +175	
Dielectric Strengh from terminals to case, AC with t=1 minute, RH<30%	Vdis	2000		v
NOTES : 1.Thermal Resistance Junction to Case.			REV. 2, Oct-2010, KTHC43	

2.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Device mounted on 135mm x 135mm x 8mm Alumium Plate Heatsink.

RATING AND CHARACTERISTIC CURVES MBRF1060

FIG.1 - FORWARD CURRENT DERATING CURVE FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT PEAK FORWARD SURGE CURRENT, AMPERES 10 150 AVERAGE FORWARD CURRENT AMPERES WITH HEATSINK 125 8 100 6 75 4 50 2 25 RESISTIVE OR INDUCTIVE LOAD 8.3ms Single Half-Sine-Way 0 ∟ 25 0 100 50 2 5 10 50 75 100 125 150 175 20 CASE TEMPERATURE ,°C NUMBER OF CYCLES AT 60Hz FIG.3 - TYPICAL REVERSE CHARACTERISTICS FIG.4 - TYPICAL FORWARD CHARACTERISTICS 100 100 INSTANTANEOUS REVERSE CURRENT, (mA) INSTANTANEOUS FORWARD CURRENT, (A) 10 TJ = 125°C 10 1 TI = 100°C = TJ = 75℃ 0.1 1 0.01 TJ = 25℃ TJ = 25℃ PULSE WIDTH 300us 2% Duty cycle 0.001 0.1 0.7 1.0 0.1 0.2 0.3 0.4 0.5 0.6 0.8 0.9 0 120 10 20 60 80 100 40 PERCENT OF RATED PEAK REVERSE VOLTAGE, (%) INSTANTANEOUS FORWARD VOLTAGE, (VOLTS) FIG.5 - TYPICAL JUNCTION CAPACITANCE 10000 1000 CAPACITANCE, (pF) 100 10 -----TJ = 25℃, f= 1MHz 1 0.1 10 100 1 **REVERSE VOLTAGE**, VOLTS

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